NPN Epitaxial Planar Silicon Transistor

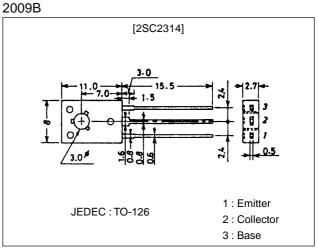


# 2SC2314

## 27MHz CB Transceiver Driver Applications

### **Package Dimensions**

unit:mm



## **Specifications**

### Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>	R <sub>BE</sub> =150Ω	75	V
Collector-to-Emitter Voltage	VCER		75	V
Collector-to-Emitter Voltage	VCEO		45	V
Emitter-to-Base Voltage	VEBO		5	V
Collector Current	۱ <sub>C</sub>		1.0	A
Collector Current (Pulse)	ICP		1.5	A
Collector Dissipation	PC		750	mW
		Tc=25°C	5	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		–55 to +150	°C

#### Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	ICBO	V <sub>CB</sub> =40V, I <sub>E</sub> =0			1.0	μA
Emitter Cutoff Current	IEBO	V <sub>EB</sub> =4V, I <sub>C</sub> =0			1.0	μA
Collector-to-Base Breakdown Voltage	V <sub>(BR)</sub> CBO	I <sub>C</sub> =10μA, I <sub>E</sub> =0	75			V
Collector-to-Emitter Breakdown Voltage	V <sub>(BR)</sub> CER	$I_{C}=1mA, R_{BE}=150\Omega$	75			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I <sub>C</sub> =1mA, R <sub>BE</sub> =∞	45			V
Emitter-to-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =10μA, I <sub>C</sub> =0	5			V
* • The 2SC2314 are classified by 500mA her	as follows ·	60 D 120 100 E 200 160 E 320				

\* : The 2SC2314 are classified by 500mA  $h_{FE}$  as follows : 60 D 120 100 E 200 160 F 320

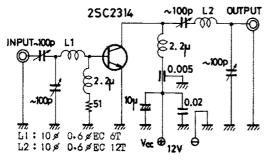
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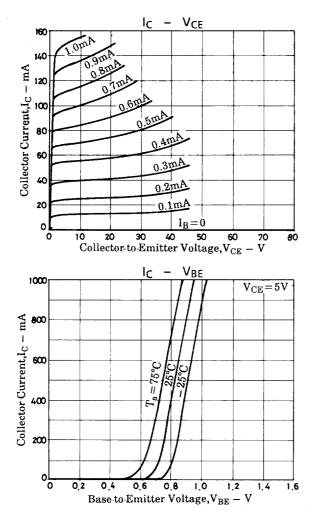
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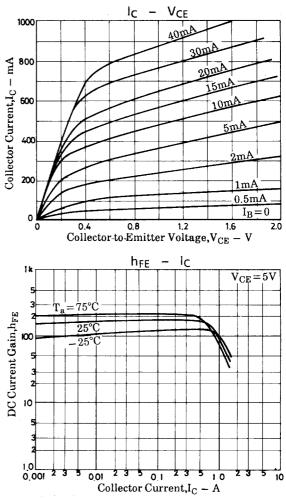
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Onit
DC Current Gain	hFE	V <sub>CE</sub> =5V, I <sub>C</sub> =500mA	60*		320*	
Gain-Bandwidth Product	fT	V <sub>CE</sub> =10V, I <sub>C</sub> =50mA	180	250		MHz
Output Capacitance	Cob	V <sub>CB</sub> =10V, f=1MHz		15	25	pF
Output Power	PO	V <sub>CC</sub> =12V, f=27MHz, Pi=35mW	1.0	1.8		W
Collector Efficiency	ης	See specified test circuit.	60			%
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =500mA, I <sub>B</sub> =50mA		0.2	0.6	V
Base-to-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =500mA, I <sub>B</sub> =50mA		0.9	1.2	V

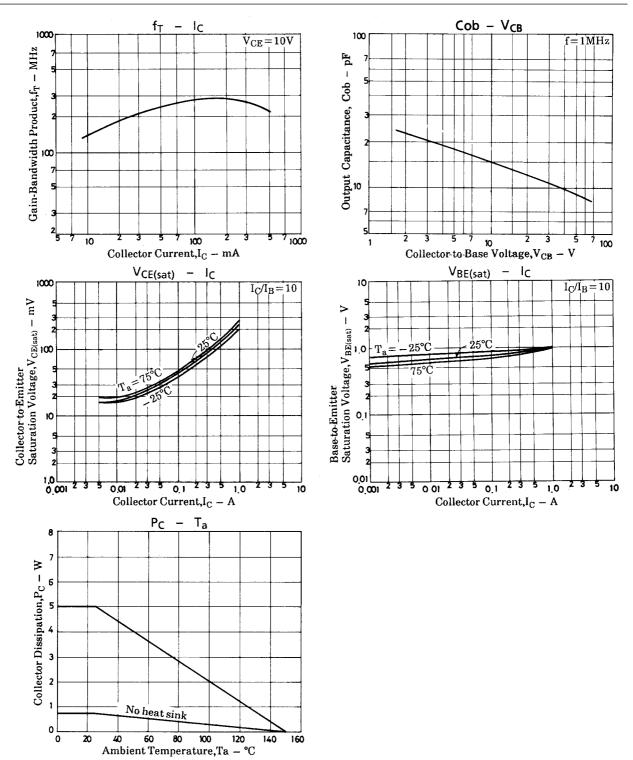
### **Collector Efficiency Test Circuit**



Unit (resistance :  $\Omega$ , capacitance : F)







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